

# 2SK1305

Silicon N-Channel MOS FET

# HITACHI

## Application

High speed power switching

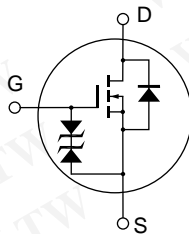
## Features

- Low on-resistance
- High speed switching
- Low drive current
- 4 V gate drive device  
— Can be driven from 5 V source
- Suitable for motor drive, DC-DC converter, power switch and solenoid drive

## Outline

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勝特力电子(上海) 86-21-34970699  
勝特力电子(深圳) 86-755-83298787  
[Http://www.100y.com.tw](http://www.100y.com.tw)

TO-220FM



1. Gate
2. Drain
3. Source

## 2SK1305

### Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	100	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	10	A
Drain peak current	I <sub>D(pulse)</sub> <sup>*1</sup>	40	A
Body to drain diode reverse drain current	I <sub>DR</sub>	10	A
Channel dissipation	Pch <sup>*2</sup>	25	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

- Notes: 1. PW ≤ 10 μs, duty cycle ≤ 1%  
2. Value at T<sub>c</sub> = 25°C

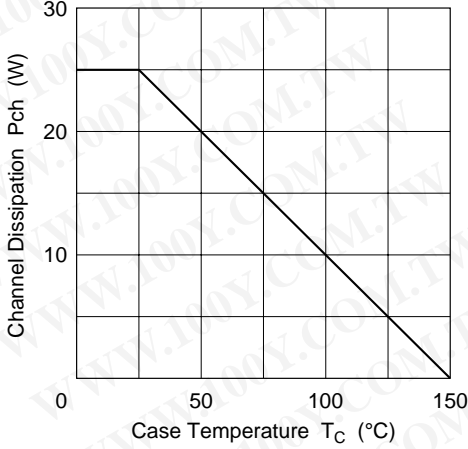
## Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	100	—	—	V	$I_D = 10 \text{ mA}$ , $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	$\pm 20$	—	—	V	$I_G = \pm 100 \text{ }\mu\text{A}$ , $V_{DS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	$\pm 10$	$\mu\text{A}$	$V_{GS} = \pm 16 \text{ V}$ , $V_{DS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	250	$\mu\text{A}$	$V_{DS} = 80 \text{ V}$ , $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	—	2.0	V	$I_D = 1 \text{ mA}$ , $V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	$R_{DS(on)}$	—	0.20	0.25	$\Omega$	$I_D = 5 \text{ A}$ , $V_{GS} = 10 \text{ V}^{*1}$
		—	0.25	0.35	$\Omega$	$I_D = 5 \text{ A}$ , $V_{GS} = 4 \text{ V}^{*1}$
Forward transfer admittance	$ y_{fs} $	4.5	7.0	—	S	$I_D = 5 \text{ A}$ , $V_{DS} = 10 \text{ V}^{*1}$
Input capacitance	$C_{iss}$	—	525	—	pF	$V_{DS} = 10 \text{ V}$ , $V_{GS} = 0$ ,
Output capacitance	$C_{oss}$	—	205	—	pF	$f = 1 \text{ MHz}$
Reverse transfer capacitance	$C_{rss}$	—	60	—	pF	
Turn-on delay time	$t_{d(on)}$	—	5	—	ns	$I_D = 5 \text{ A}$ , $V_{GS} = 10 \text{ V}$ ,
Rise time	$t_r$	—	50	—	ns	$R_L = 6 \text{ }\Omega$
Turn-off delay time	$t_{d(off)}$	—	170	—	ns	
Fall time	$t_f$	—	75	—	ns	
Body to drain diode forward voltage	$V_{DF}$	—	1.2	—	V	$I_F = 10 \text{ A}$ , $V_{GS} = 0$
Body to drain diode reverse recovery time	$t_{rr}$	—	220	—	ns	$I_F = 10 \text{ A}$ , $V_{GS} = 0$ , $di_F/dt = 50 \text{ A}/\mu\text{s}$

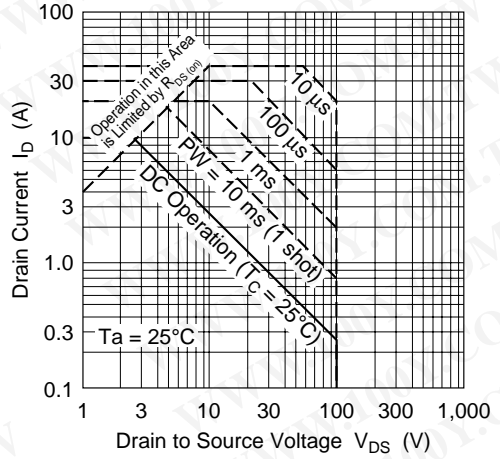
Note: 1. Pulse test

See characteristic curves of 2SK1300.

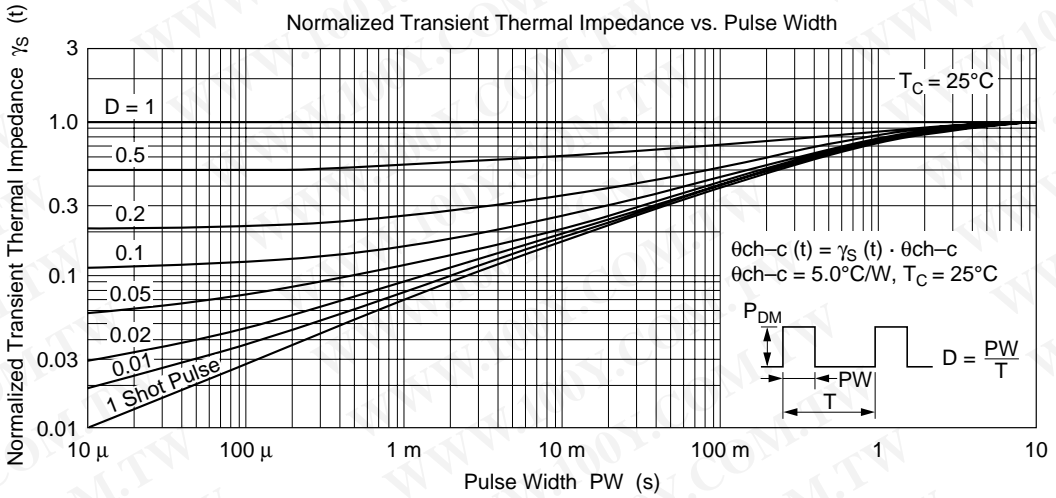
Power vs. Temperature Derating



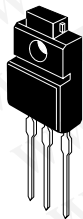
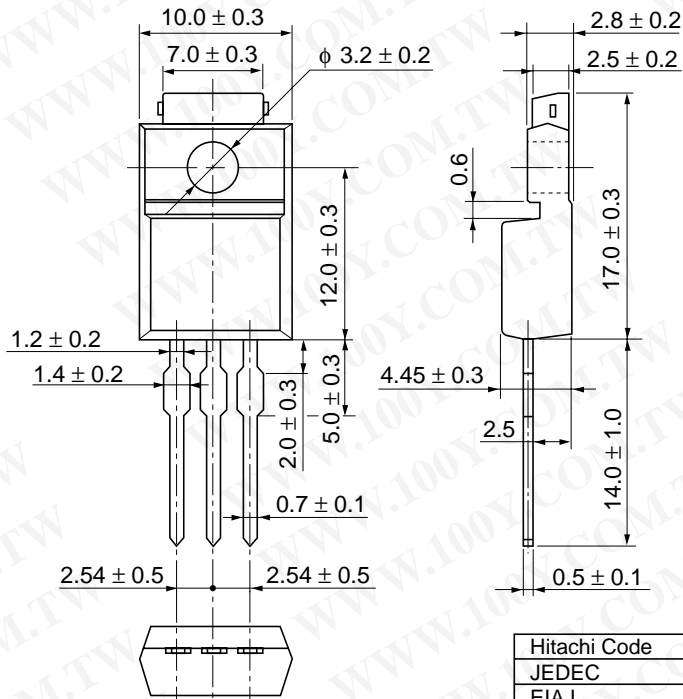
Maximum Safe Operation Area



Normalized Transient Thermal Impedance vs. Pulse Width



Unit: mm



Hitachi Code	TO-220FM
JEDEC	—
EIAJ	Conforms
Weight (reference value)	1.8 g

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